

DATA SHEET

PDTA143X series

PNP resistor-equipped transistors;

$R1 = 4.7\text{ k}\Omega$, $R2 = 10\text{ k}\Omega$

Product specification
Supersedes data of 2002 Mar 14

2003 Apr 10

PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 10 k Ω

PDTA143X series

FEATURES

- Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	–	–50	V
I _O	output current (DC)	–	–100	mA
R1	bias resistor	4.7	–	k Ω
R2	bias resistor	10	–	k Ω

DESCRIPTION

PNP resistor-equipped transistor (see “Simplified outline, symbol and pinning” for package details).

PRODUCT OVERVIEW

TYPE NUMBER	PACKAGE		MARKING CODE	NPN COMPLEMENT
	PHILIPS	EIAJ		
PDTA143XE	SOT416	SC-75	35	PDTC143XE
PDTA143XEF	SOT490	SC-89	41	PDTC143XEF
PDTA143XK	SOT346	SC-59	25	PDTC143XK
PDTA143XM	SOT883	SC-101	DN	PDTC143XM
PDTA143XS	SOT54 (TO-92)	SC-43	TA143X	PDTC143XS
PDTA143XT	SOT23	–	*31 ⁽¹⁾	PDTC143XT
PDTA143XU	SOT323	SC-70	*46 ⁽¹⁾	PDTC143XU

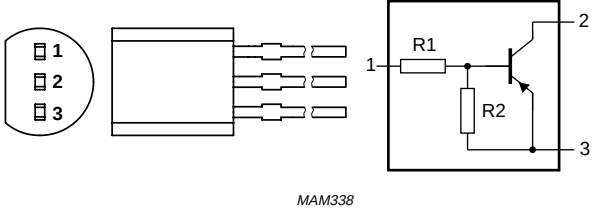
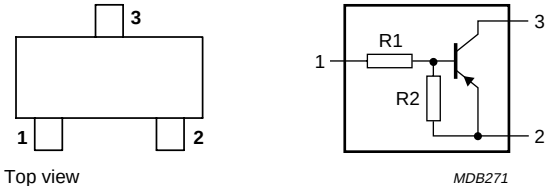
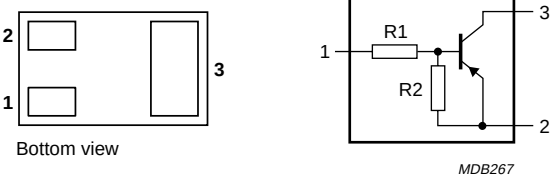
Note

- * = p: Made in Hong Kong.
* = t: Made in Malaysia.
* = W: Made in China.

PNP resistor-equipped transistors;
R1 = 4.7 kΩ, R2 = 10 kΩ

PDTA143X series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PINNING	
		PIN	DESCRIPTION
PDTA143XS		1 2 3	base collector emitter
PDTA143XE PDTA143XEF PDTA143XK PDTA143XT PDTA143XU		1 2 3	base emitter collector
PDTA143XM		1 2 3	base emitter collector

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PDTA143X series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	–	–50	V
V _{CEO}	collector-emitter voltage	open base	–	–50	V
V _{EBO}	emitter-base voltage	open collector	–	–10	V
V _I	input voltage positive negative		–	+7	V
			–	–20	V
I _O	output current (DC)		–	–100	mA
I _{CM}	peak collector current		–	–100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	SOT54	note 1	–	500	mW
	SOT23	note 1	–	250	mW
	SOT346	note 1	–	250	mW
	SOT323	note 1	–	200	mW
	SOT416	note 1	–	150	mW
	SOT490	notes 1 and 2	–	250	mW
	SOT883	notes 2 and 3	–	250	mW
T _{stg}	storage temperature		–65	+150	°C
T _j	junction temperature		–	150	°C
T _{amb}	operating ambient temperature		–65	+150	°C

Notes

1. Refer to standard mounting conditions.
2. Reflow soldering is the only recommended soldering method.
3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT416	note 1	833	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W

Notes

1. Refer to standard mounting conditions.
2. Reflow soldering is the only recommended soldering method.
3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

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CHARACTERISTICS

T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0	–	–	-100	nA
I _{CEO}	collector-emitter cut-off current	V _{CE} = -30 V; I _B = 0	–	–	-1	μ A
		V _{CE} = -30 V; I _B = 0; T _j = 150 °C	–	–	-50	μ A
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0	–	–	-600	μ A
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -10 mA	50	–	–	
V _{CEsat}	collector-emitter saturation voltage	I _C = -10 mA; I _B = -0.5 mA	–	–	-150	mV
V _{i(off)}	input-off voltage	I _C = -100 μ A; V _{CE} = -5 V	–	-0.9	-0.3	V
V _{i(on)}	input-on voltage	I _C = -20 mA; V _{CE} = -0.3 V	-2.5	-1.5	–	V
R1	input resistor		3.3	4.7	6.1	k Ω
$\frac{R2}{R1}$	resistor ratio		1.7	2.1	2.6	
C _c	collector capacitance	I _E = i _e = 0; V _{CB} = -10 V; f = 1 MHz	–	–	3	pF

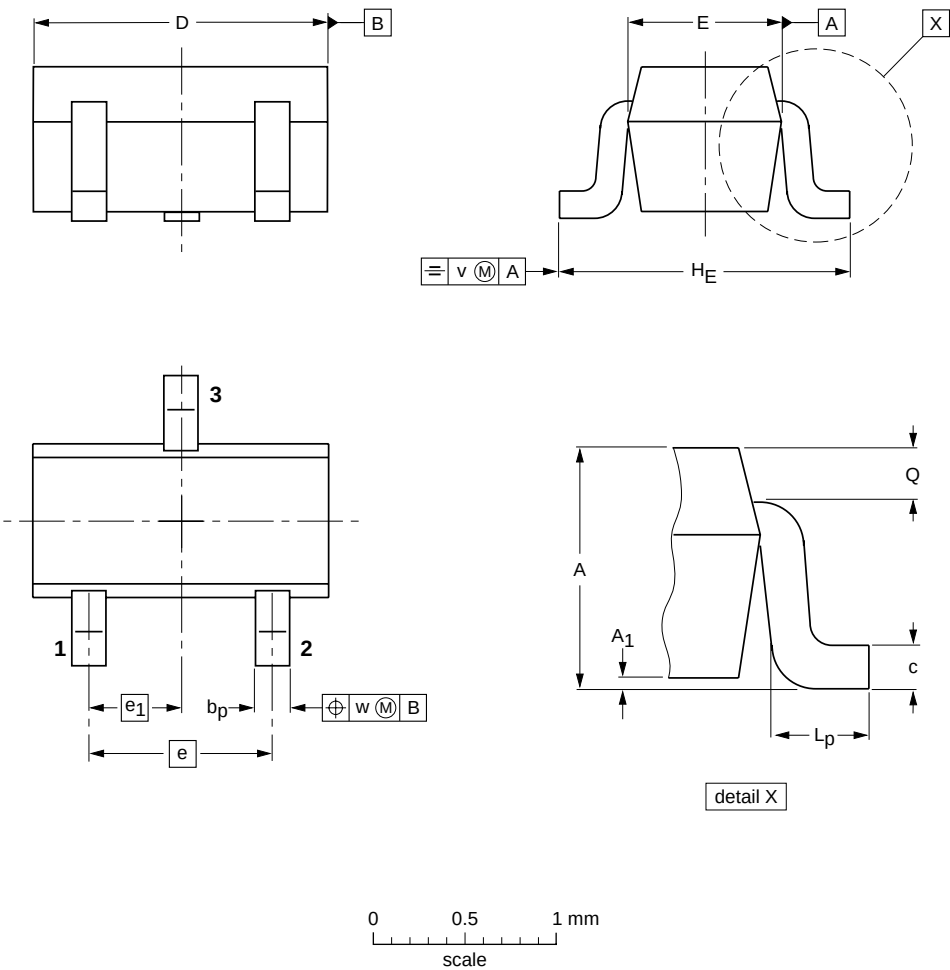
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PACKAGE OUTLINES

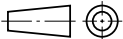
Plastic surface mounted package; 3 leads

SOT416



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

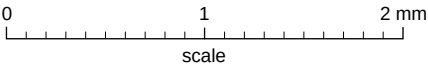
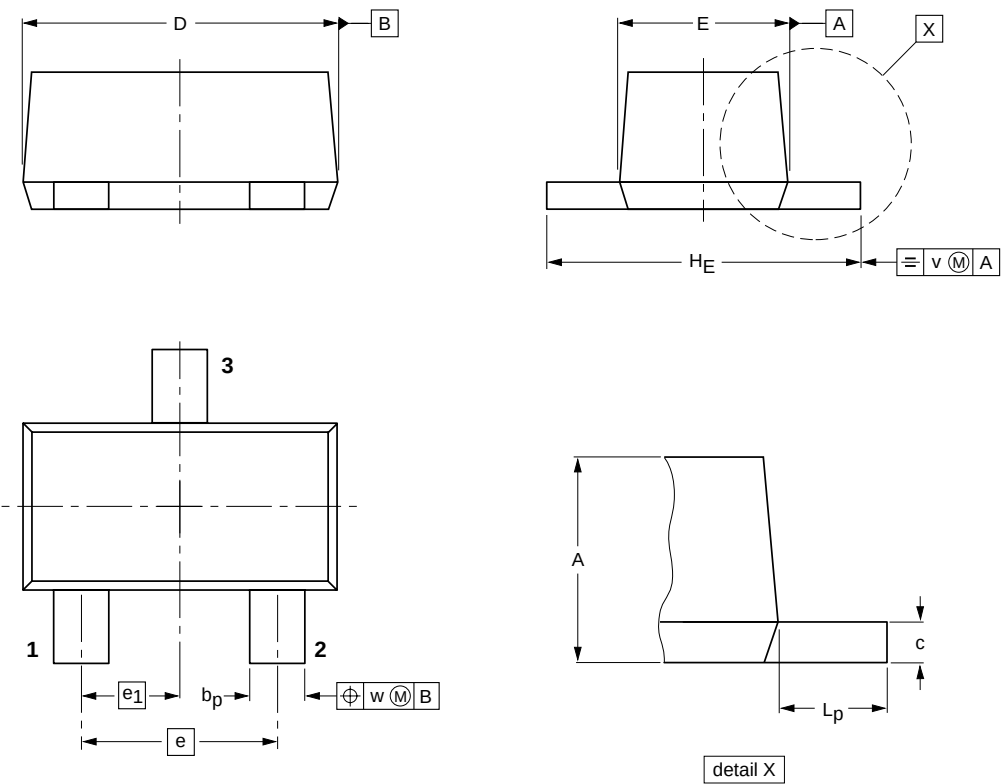
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT416			SC-75			97-02-28

PNP resistor-equipped transistors;
R1 = 4.7 kΩ, R2 = 10 kΩ

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Plastic surface mounted package; 3 leads

SOT490



DIMENSIONS (mm are the original dimensions)

UNIT	A	b _p	c	D	E	e	e ₁	H _E	L _p	v	w
mm	0.8 0.6	0.33 0.23	0.2 0.1	1.7 1.5	0.95 0.75	1.0	0.5	1.7 1.5	0.5 0.3	0.1	0.1

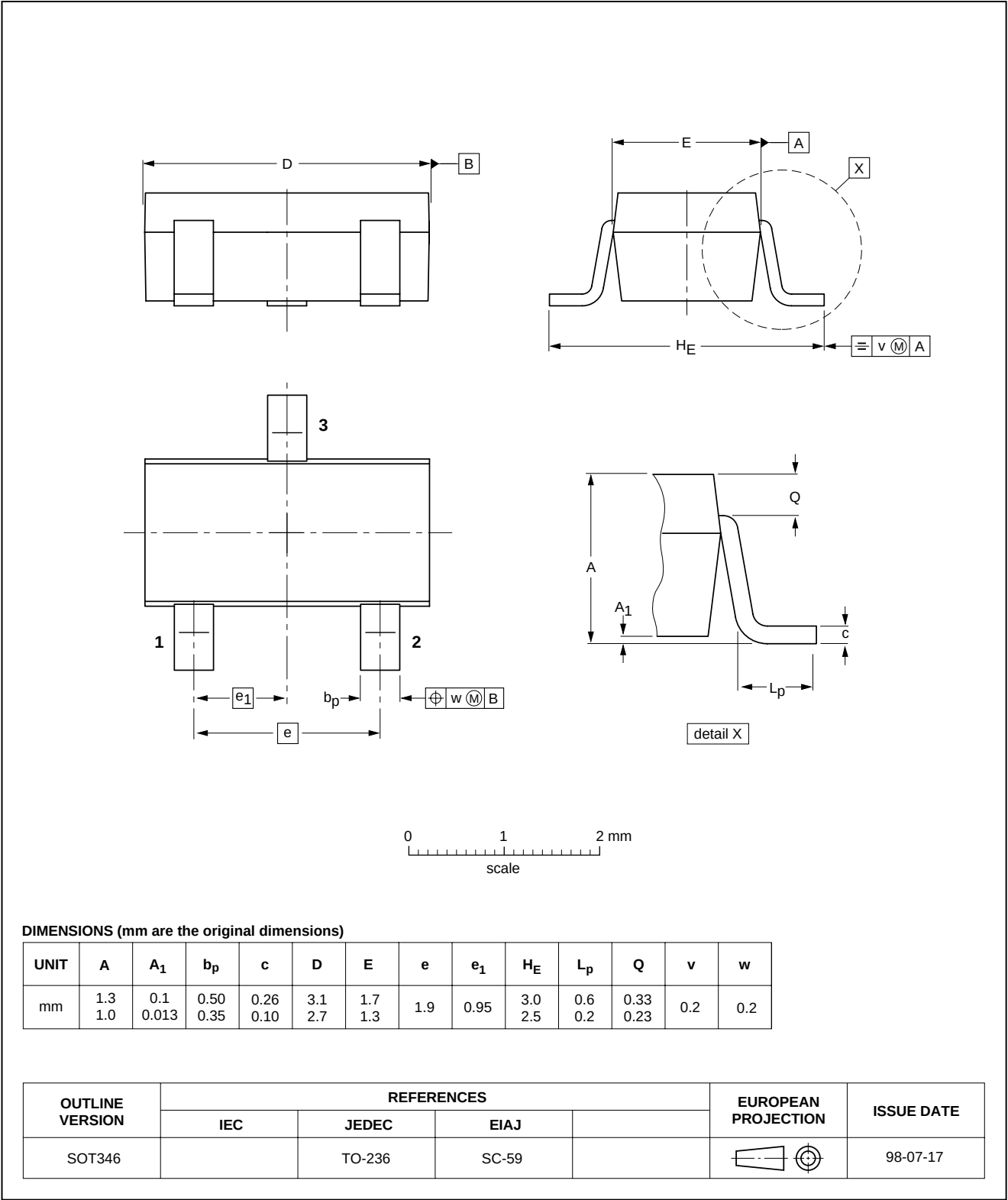
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT490			SC-89			98-10-23

PNP resistor-equipped transistors;
R1 = 4.7 kΩ, R2 = 10 kΩ

PDTA143X series

Plastic surface mounted package; 3 leads

SOT346

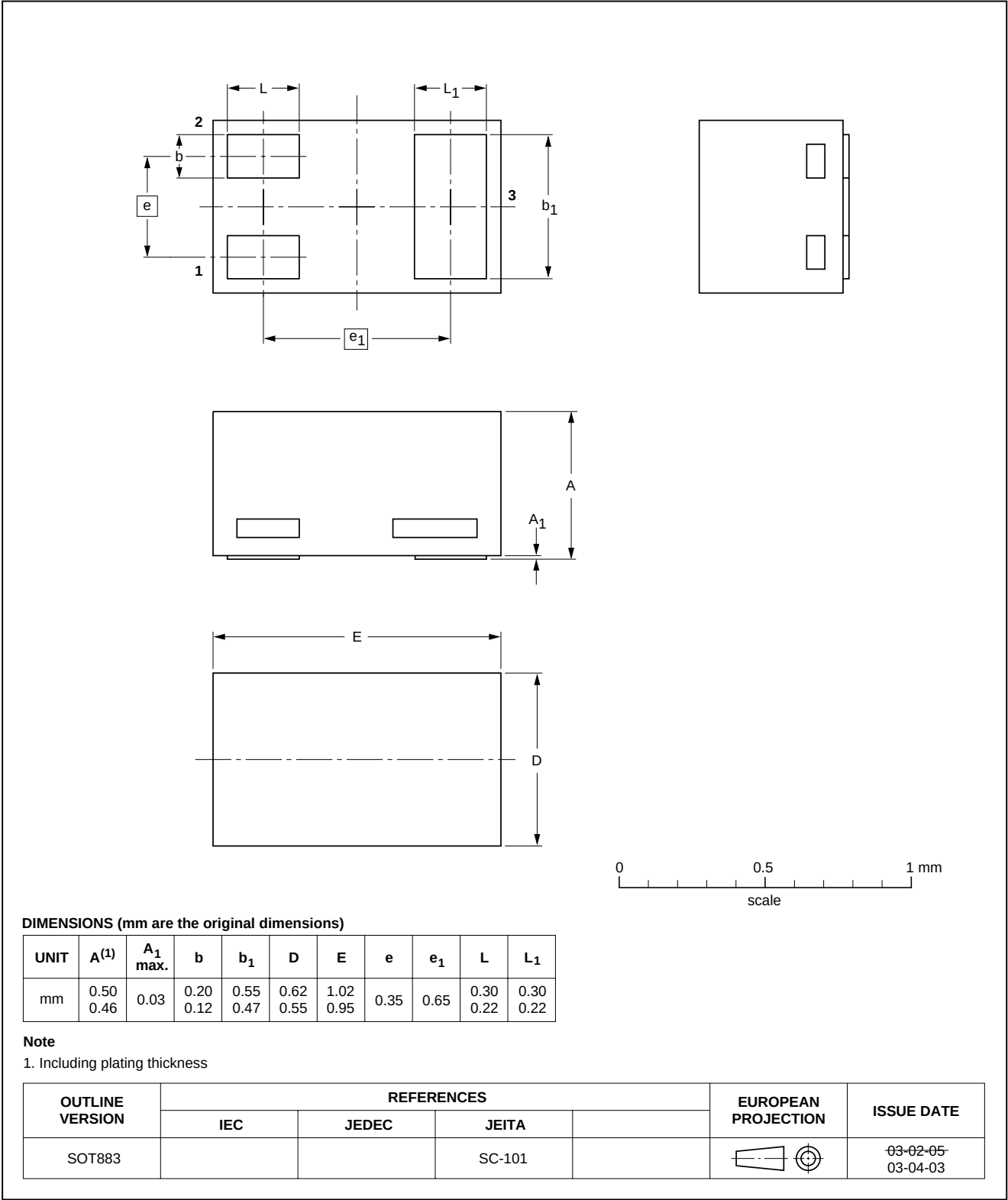


PNP resistor-equipped transistors;
R1 = 4.7 kΩ, R2 = 10 kΩ

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Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883

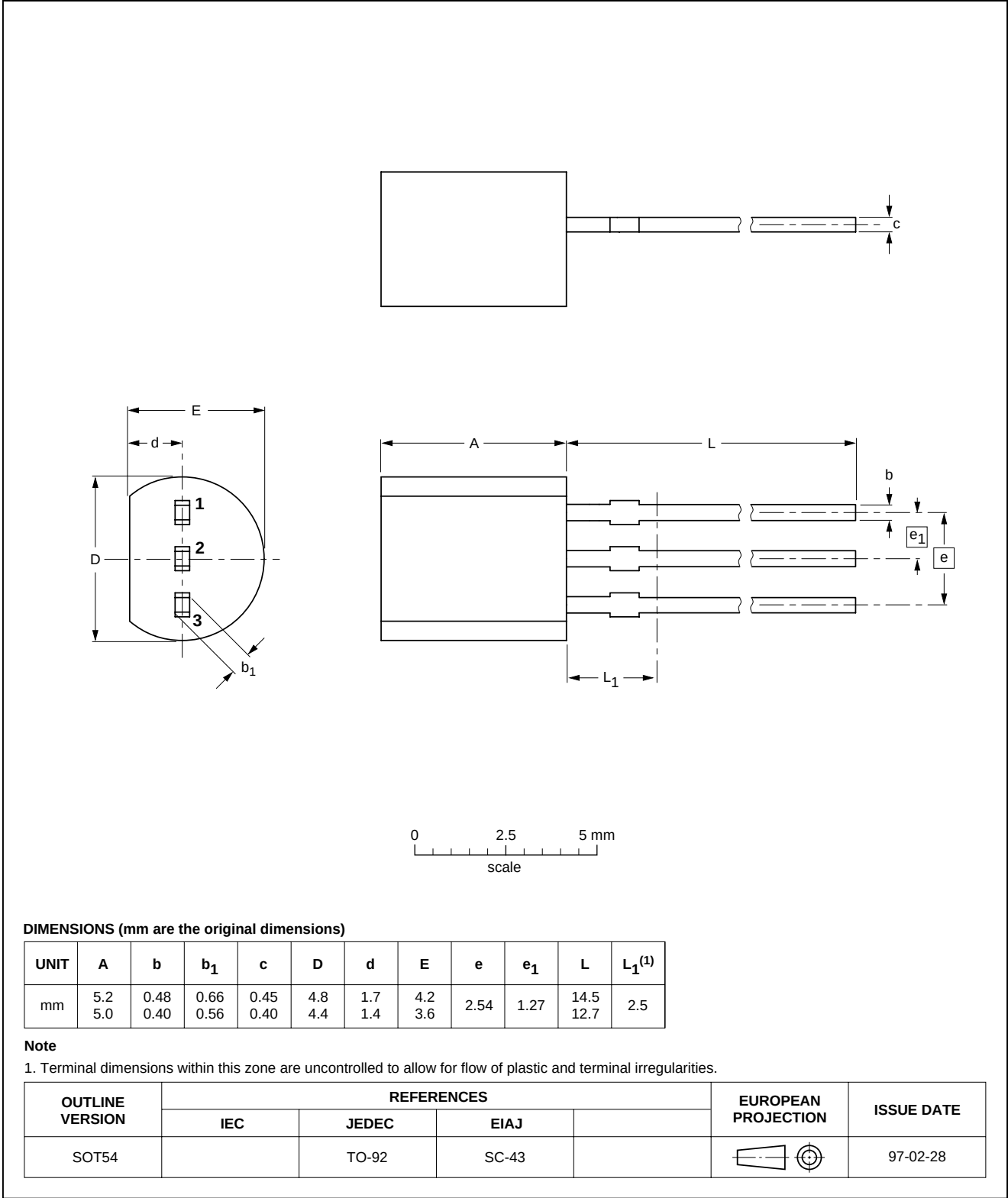


PNP resistor-equipped transistors;
R1 = 4.7 kΩ, R2 = 10 kΩ

PDTA143X series

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

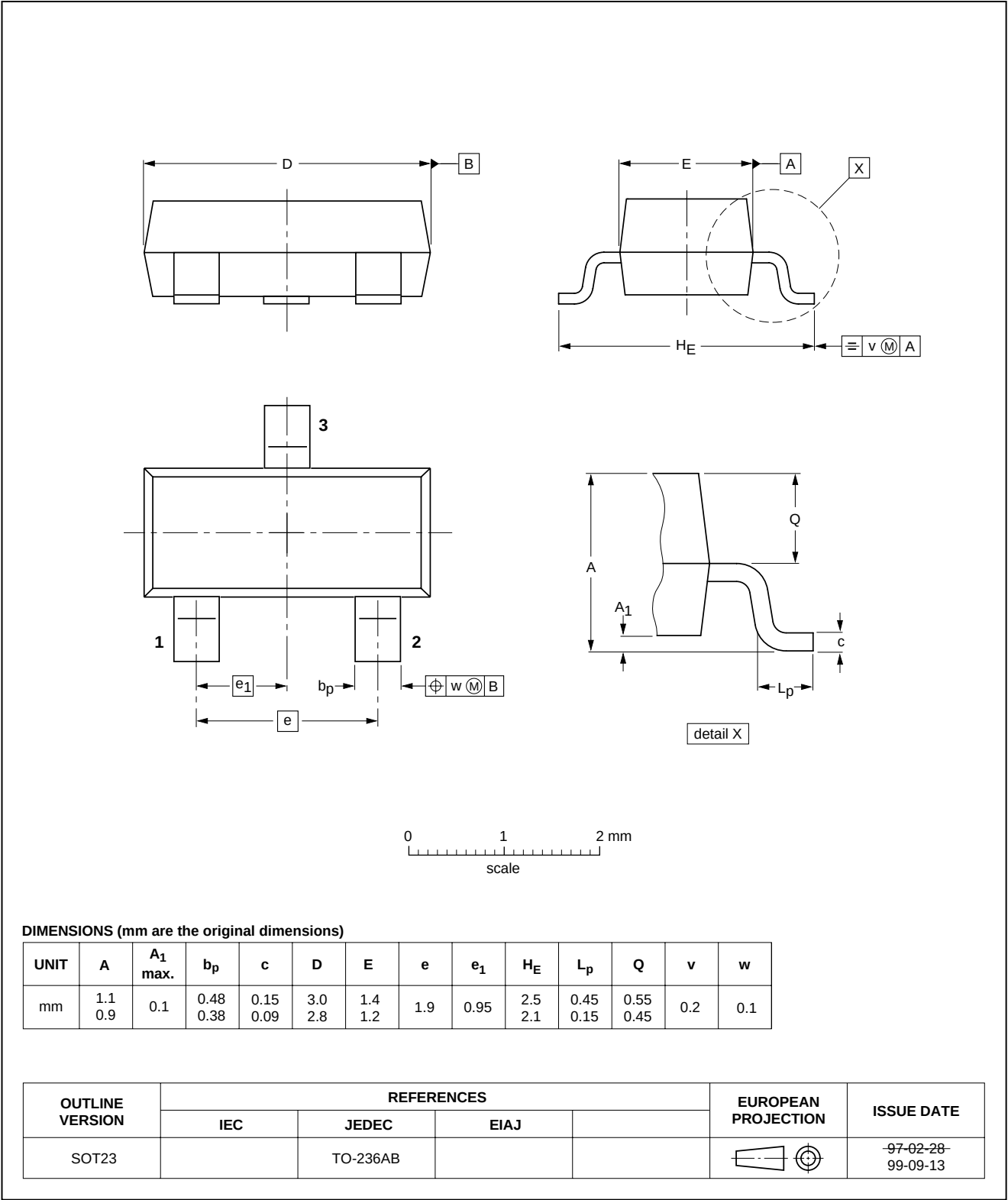


PNP resistor-equipped transistors;
R1 = 4.7 kΩ, R2 = 10 kΩ

PDTA143X series

Plastic surface mounted package; 3 leads

SOT23

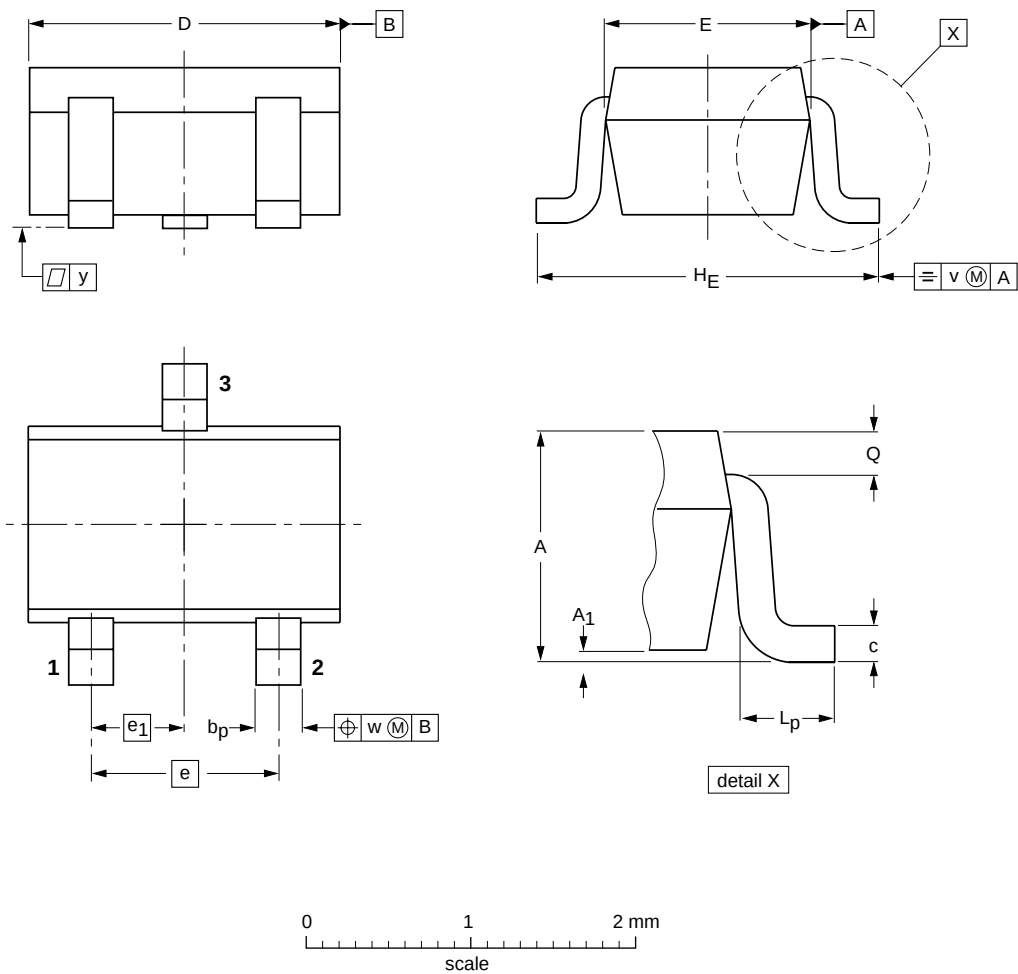


PNP resistor-equipped transistors;
R1 = 4.7 kΩ, R2 = 10 kΩ

PDTA143X series

Plastic surface mounted package; 3 leads

SOT323



DIMENSIONS (mm are the original dimensions)

UNIT	A	A1 max	bp	c	D	E	e	e1	HE	Lp	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT323			SC-70			97-02-28

PNP resistor-equipped transistors; R1 = 4.7 kΩ, R2 = 10 kΩ

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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NOTES

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NOTES

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